TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

2 S A 1 3 1 6

FOR LOW NOISE AUDIO AMPLIFIER APPLICATIONS AND RECOMMENDED FOR THE FIRST STAGES OF MC HEAD AMPLIFIERS

• Very Low Noise in the Region of Low Signal Source Impedance Equivalent Input Noise Voltage : $E_n = 0.6 nV / \sqrt{Hz}$ (Typ.)

• Low Pulse Noise. Low 1/f Noise

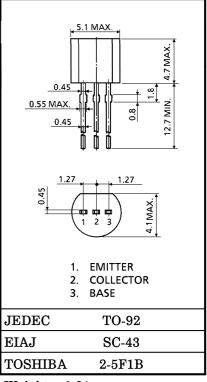
• Low Base Spreading Resistance : r_{bb} '=2.0 Ω (Typ.)

• Complementary to 2SC3329

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	v_{CEO}	-80	V
Emitter-Base Voltage	v_{EBO}	-5	V
Collector Current	$I_{\mathbf{C}}$	-100	mA
Base Current	I_{B}	-20	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	400	mW
Junction Temperature	Tj	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C

Unit in mm

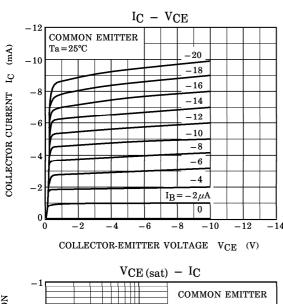


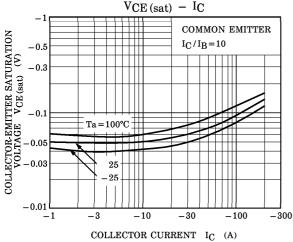
Weight: 0.21g

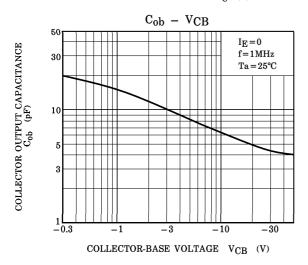
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

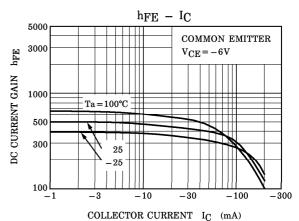
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I _{CBO}	$V_{CB} = -80V, I_{E} = 0$	_	_	-0.1	μ A
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -5V, I_C = 0$	_	_	-0.1	μ A
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{C} = -1 \text{mA}, I_{B} = 0$	-80	_	1	V
DC Current Gain	hFE (Note)	$V_{CE} = -6V, I_{C} = -2mA$	200	_	700	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$I_{C} = -10 \text{mA}, I_{B} = -1 \text{mA}$	_	_	-0.1	V
Base-Emitter Voltage	$v_{ m BE}$	$V_{CE} = -6V$, $I_C = -2mA$	_	-0.6	ı	V
Base Spreading Resistance	r _{bb} ,	$V_{\text{CE}} = -6V$, $I_{\text{C}} = -1\text{mA}$, $f = 100\text{MHz}$	_	2.0	1	Ω
Transition Frequency	$ m f_T$	$V_{CE} = -6V, I_{C} = -1mA, f = 100MHz$	_	50	1	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V, I_{E} = 0, f = 1MHz$	_	6.2	ı	pF
Noise Figure	NF	$V_{CE} = -6V, I_{C} = -0.1 \text{mA}$ f=10Hz, R _G =10k Ω	_	1	6	
		$V_{\text{CE}} = -6\text{V}, I_{\text{C}} = -0.1\text{mA}$ $f = 1\text{kHz}, R_{\text{G}} = 10\text{k}\Omega$	_	0.5	2	dB
		$V_{CE} = -6V, I_{C} = -0.1 \text{mA}$ f=1kHz, R _G =100 Ω	_	2.5	_	

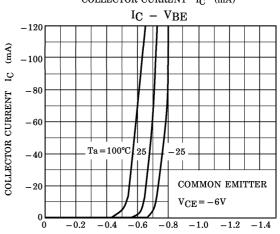
Note : hFE Classification $GR: 200{\sim}400$, BL: 350 ${\sim}700$

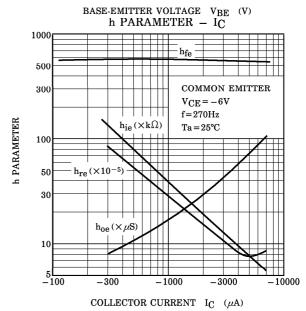


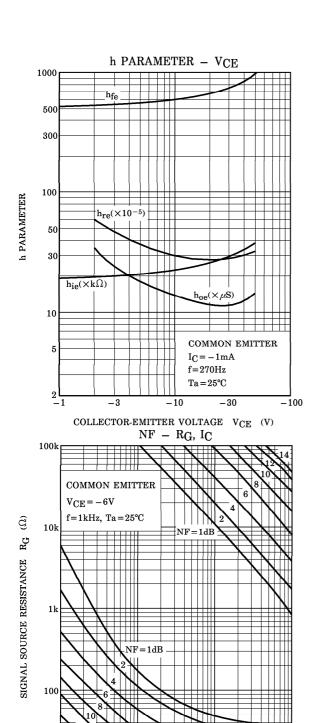




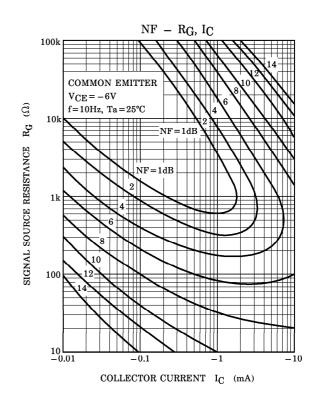


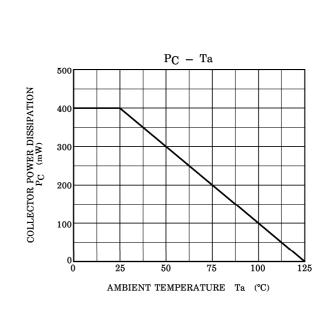






COLLECTOR CURRENT IC (mA)





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